
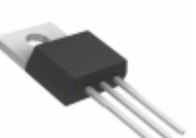
	<h2 style="color: red;">FQP12P20</h2>
	<p><b>Hersteller-Teilenummer:</b> FQP12P20</p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 200V 11.5A TO-220</p> <p><b>Datenblätter:</b> <a href="#">1.FQP12P20.pdf</a> <a href="#">2.FQP12P20.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 26303 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQP12P20
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 200V 11.5A TO-220
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	26303 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	120W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	11.5A (Tc)
Rds On (Max) @ Id, Vgs	470 mOhm @ 5.75A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1200pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube

FQP12P20 ist neu im Original, Suche FQP12P20 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP12P20 Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FQP12P20: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQP13N06L</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 13.6A TO-220</p>	 <p><b>FQP12P10</b> Fairchild/ON Semiconductor MOSFET P-CH 100V 11.5A TO-220</p>	 <p><b>FQP12N60C</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 12A TO-220</p>	 <p><b>FQP13N06L</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 13.6A TO-220</p>
 <p><b>FQP12N65C</b> VB FQP12N65C VB</p>	 <p><b>FQP13N06</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 13A TO-220</p>	 <p><b>FQP12P10</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 11.5A TO-220</p>	 <p><b>FQP12P20</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 11.5A TO-220</p>

### heiße Teile

Mehr

⊗ FQP10N60C	↔ FQP10N60C	⇒ FQP10N60CF	D FQP10N60C_07	⇒ FQP10N65
⊣ FQP10N65C	⊗ FQP10N80	D FQP11N40C	⇒ FQP11N40C	⇒ FQP11N50CF
⊗ FQP11N50CF	⊣ FQP11N60	⊗ FQP11N60C	↔ FQP11N65C	⇒ FQP11P06
D FQP11P06	⊗ FQP12N20	⊣ FQP12N60	⊗ FQP12N60	⇒ FQP12N60C
⇒ FQP12N60C	↔ FQP12N65C	⊗ FQP12P10	⊣ FQP12P10	⇒ FQP12P20
↔ FQP13N06	⇒ FQP13N06	D FQP13N06L	⊗ FQP13N06L	⊣ FQP13N10
⊗ FQP13N10	D FQP13N10L	⇒ FQP13N10L	↔ FQP13N50	⇒ FQP13N50
⊣ FQP13N50C	⊗ FQP13N50C	↔ FQP13N60C	⇒ FQP140N03	⇒ FQP140N03L
⊗ FQP14N15	⊣ FQP14N15	⊗ FQP14N30	D FQP14N30	⇒ FQP14N80
↔ FQP14N80C	⊗ FQP15N16	⊣ FQP15N30	⊗ FQP15N50	⇒ FQP15N60

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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